# THE ELECTRIC PROPERTY OF THE PEROVSKITE COMPOUND Ca<sub>1.x</sub>Nd<sub>x</sub>MnO<sub>3</sub>

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Abstract: The perovskite compounds Ca,  $Md_iMnO_i$  (x=0; 0.1: 0.3: 0.5; 0.7: 0.9; 0.95) have been made by the ceramic technology. The crystal structure has been determined and the Rietveld refinement method has been used for the calculation of the structure parameters. The samples have semiconducting behaviour at all temperatures and depending on their composition they can be the n-type or p-type semiconductor.

# 1. Introduction

Ideal perovskite compound CaMnO<sub>3</sub> with the cubic structure is the isolator and antiferromagnetic. Preparing by ceramic method, it must be sintered at high temperature in the air, its composition became non-stochiometry of CaMnO<sub>35</sub> and the mix-valence state appeared, it called the seft-doping phenomenon. If a part of Ca is substituted by ion having valence higher than +2, a respective part of  $Mn^{*4}$  transfers to  $Mn^{*3}$ , the electric and magnetic properties of the compound is changed [1]

In this work, the compounds  $Ca_{i,k}Nd_kMnO_3$  (x=0; 0.1; 0.3; 0.5; 0.7; 0.9: 0.95) have been prepared and the influence of the composition and the structure on the electric property was investigated.

#### 2. Experiment

The samples were prepared using the ceramic technique. The materials are  $CaCO_3$ (99%)  $Ma_2O_3$  (99.9%)  $MnCO_3$  (99.9%). The samples with the rectangular form were sintered at 1300°C for 10hs in air. The phase of the samples were indentified by X-ray powder diffraction. The electric resistivity was measured by two electrods technique in the temperature range of 10K-500K.

### 3. Results and discussion

The structure refinement was carried out by Rietveld analysis of X-ray powder diffraction data and the structure parameters have shown in the Tab.1. With increasing of Neodium content (x), the  $Mn^{-3}$  ions having the radius higher than one of  $Mn^{-4}$  are increased and it leads to the increasing of lattice constant, volume and distance of Mn-0 [2,3].

	Samples	Structure	a(Å)	b (Å)	c(Å)	V(Å)	Mn-O distance	Mn-O-Mn angle
$     \begin{array}{c}       1 \\       2 \\       3 \\       4 \\       5     \end{array} $	$\begin{array}{c} CaMnO_3\\ Ca_{a,2}Nd_{a,1}MnO_3\\ Ca_{a,2}Nd_{a,3}MnO_3\\ Ca_{a,2}Nd_{a,3}MnO_3\\ Ca_{a,2}Nd_{a,3}MnO_3\\ Ca_{a,3}Nd_{a,3}MnO_3 \end{array}$	Orthorhombic Orthorhombic Orthorhombic Tetragonal Orthorhombic	5.259 5.295 5.332 3.800 5.405	5.264 5.294 5.334 3.800 5.443	7.458 7.480 7.547 7.591 7.640	206.5 209.7 214.7 219.0 224.7	1.876 1.893 1.888 1.903 1.917	165.8 159.2 167.0 169.0 170.0

Table 1. The structure parameters

The results of the electrical resistivity measurements are shown in Fig.1. All samples are semiconductors with a negative temperature coefficient of resistivity. There is the metal-insulator transition in the two samples with x = 0.7; 0.9 at 420K and 430 K respectively. Fig.2 shows the dependence of lnp vs 1/T of the samples. The activation energy calculated from the linear portion of lnp vs 1/T and the resistivity has been shown in the Tab.2.

Table 2. Resistivity ρ (Ωcm) (T<sub>mem</sub>) & Activation energy E (eV)

0.261
0.135
0.083
0.079
0.215
0.221

In the range of  $0 \le x \le 0.5$  the value of  $\rho$  ( $\Omega \le m$ ) and E (eV) were decreased and increased in the range of  $0.5 \le x \le 0.5$ . It can be explained by the influence of the ratio  $Mn^{-3}/Mn^{-4}$  and the distance Mn-O as well as the angle of Mn-O-Mn.



Fig 1. The resistivity temperature dependence curvers of the samples



Fig.2. The curvers lnp · 1000/T of the samples



Fig.3. The Seebeck coefficient of the samples at the room temperature

The measuring result of the Seebeck coefficient at room temperature (Fig.3) shown that, depending on Nd concentration, the materials were the semiconductor of n-type (x=0.+0.5) and semiconductor of p-type (x=0.+0.5)

# 4. Conclusion

The samples of  $Ca_{1_A}Md_AmO_3$  (x=0; 0.1; 0.3; 0.7; 0.9) are the orthorhombic perovskite type structure. The sample  $Ca_{a_3}Ma_{a_3}MnO_3$  is tetragonal. With increasing of Nd content the resistivity of the sample has a minimum at x=0.5. At high temperature, the metal-insulator transistion occurs in the composition range of  $0.7\le x\le 0.9$ , it is like the case of [3.4]. Depending on Nd concentration, the materials were the semiconductor of n-type (x=0-0.5) or semiconductor of p-type (x=0.7-0.95).

## References

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